

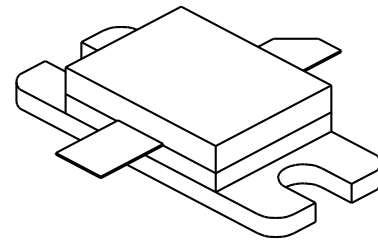
# JTDA 150A

145 Watts, 36 Volts, Pulsed  
Avionics 960 - 1215 MHz

## GENERAL DESCRIPTION

The JTDA-150A is a high power COMMON BASE bipolar transistor. It is designed for pulsed systems in the frequency band 960-1215 MHz. The transistor includes input and output prematch for broadband performance. The device has gold thin-film metallization and diffused ballasting for proven highest MTTF. Low thermal resistance Solder Sealed Package reduces junction temperature, extends life.

## CASE OUTLINE 55KT, STYLE 1



## ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C<sup>2</sup> 350 Watts

### Maximum Voltage and Current

BVces Collector to Base Voltage 50 Volts  
BVebo Emitter to Base Voltage 3.5 Volts  
Ic Collector Current 15 Amps

### Maximum Temperatures

Storage Temperature - 65 to + 200°C  
Operating Junction Temperature + 200°C

## ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout	Power Out	F = 960-1215 MHz	145			Watts
Pin	Power Input	Vcc = 36 Volts			24	Watts
Pg	Power Gain	PW = Note 1	8			dB
η <sub>c</sub>	Collector Efficiency	DF = Note 1		45		%
VSWR	Load Mismatch Tolerance	F = 1215 MHz			3:1	

BVebo	Emitter to Base Breakdown	Ie = 20 mA	3.5			Volts
BVces	Collector to Emitter Breakdown	Ic = 60 mA	55			Volts
h <sub>FE</sub>	DC - Current Gain	Ic = 5.0A, Vce = 5 V	20			
θ <sub>jc</sub> <sup>2</sup>	Thermal Resistance				0.5	°C/W

Note 1: JTIDS Pulse = 7 Micorseconds On / Off for 3.3 Millisec, 22 % Long term duty

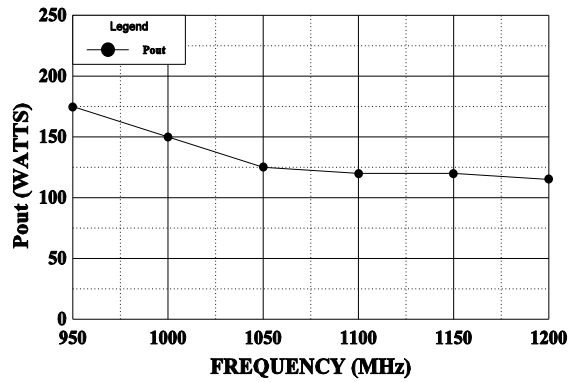
2: At rated pulse conditions

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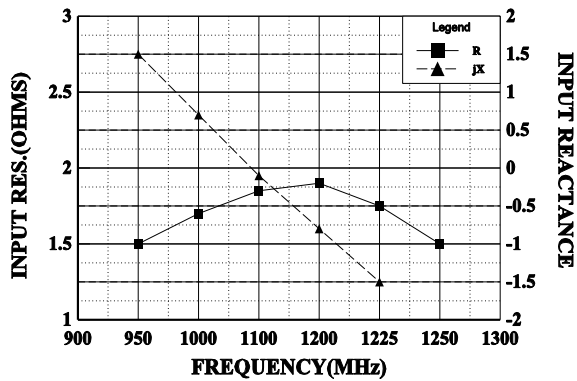
**POWER OUTPUT vs FREQUENCY**

Vcc = 36 V, Pin = 25 W



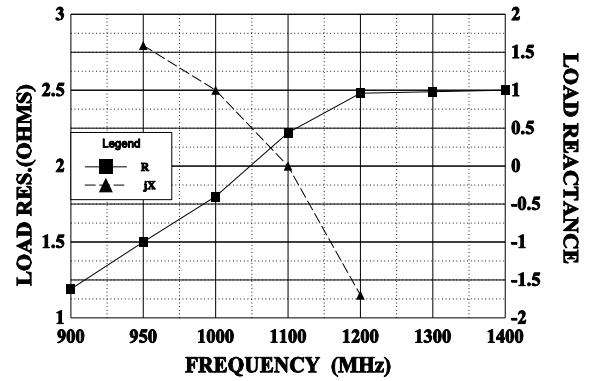
**SERIES INPUT IMPEDANCE vs FREQUENCY**

Vcc = 36 V, Po = 145 W



**SERIES LOAD IMPEDANCE vs FREQUENCY**

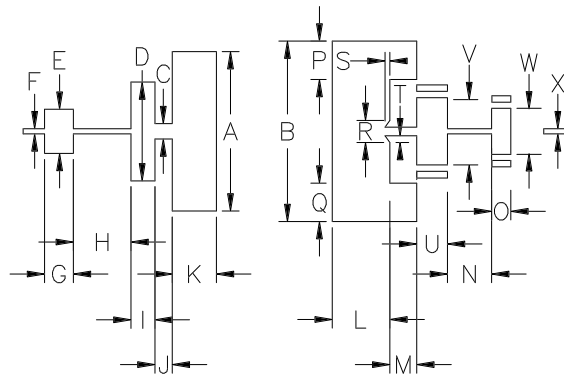
Vcc = 36 V, Po = 145 W



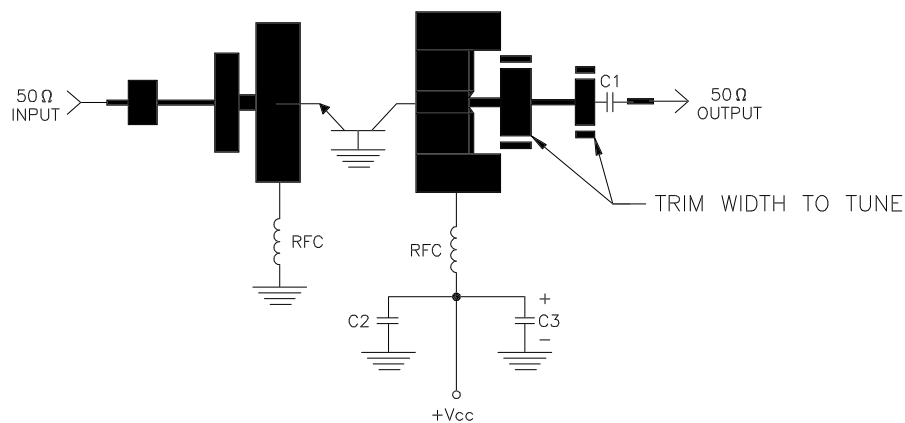
REVISIONS

ZONE	REV	DESCRIPTION	DATE	APPROVED
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DIM	INCHES
A	.830
B	.940
C	.080
D	.515
E	.230
F	.026
G	.150
H	.300
I	.125
J	.090
K	.230
L	.300
M	.140
N	.230
O	.100
P	.200
Q	.200
R	.115
S	.025
T	.035
U	.160
V	.350
W	.240
X	.026



JTDA 150A TEST CIRCUIT



DIELECTRIC = ROGERS 6010  
 $\epsilon_r = 10.2, t = 25$   
 C1, C2 = 82pF CHIP ATC "A"  
 C3 = 1000 MFD @ 50V  
 RFC = 5 turns #22 wire 1/16" I.D.

This datasheet has been download from:

[www.datasheetcatalog.com](http://www.datasheetcatalog.com)

Datasheets for electronics components.